

1.1 GHz Low-Noise Operational Amplifier

- **Bandwidth: 1.1GHz (Gain=+2)**
- **Quiescent current: 16.6 mA**
- **Slew rate: 1800V/**µ**s**
- **Input noise: 1.3nV/**√**Hz**
- **Distortion: SFDR = -78dBc (10MHz, 2Vp-p)**
- **Output stage optimized for driving 100**Ω **loads**
- **Tested on 5V power supply**

Description

The TSH330 is a current feedback operational amplifier using a very high-speed complementary technology to provide a large bandwidth of 1.1GHz in gain of 2 while drawing only 16.6mA of quiescent current. In addition, the TSH330 offers 0.1dB gain flatness up to 160MHz with a gain of 2. With a slew rate of 1800V/us and an output stage optimized for driving a standard 100Ω load, this device is highly suitable for applications where speed and low-distortion are the main requirements.

The TSH330 is a single operator available in the SO8 plastic package, saving board space as well as providing excellent thermal and dynamic performances.

Applications

- **Communication & video test equipment**
- **Medical instrumentation**
- **ADC drivers**

Order Codes

Pin Connections (top view)

1 Absolute Maximum Ratings

1) All voltages values are measured with respect to the ground pin.

2) Differential voltage are non-inverting input terminal with respect to the inverting input terminal.

3) The magnitude of input and output voltage must never exceed V_{CC} +0.3V.

4) Short-circuits can cause excessive heating. Destructive dissipation can result from short circuit on amplifiers.

5) Human body model, 100pF discharged through a 1.5kΩ resistor into pMin of device.

6) This is a minimum Value. Machine model ESD, a 200pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor < 5Ω), into pin to pin of device.

Table 2. Operating conditions

1) Tested in full production at 5V (±2.5V) supply voltage.

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2 Electrical Characteristics

Table 3. Electrical characteristics for V_{CC}= ±2.5Volts, T_{amb}=+25°C (unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
	DC performance					
V_{io}	Input Offset Voltage Offset Voltage between both inputs	T_{amb}	-3.1	0.18	$+3.1$	mV
		T_{min} < T_{amb} < T_{max}		0.8		
$\Delta V_{\rm io}$	V _{io} drift vs. Temperature	T_{min} < T_{amb} < T_{max}		1.6		μ V/°C
$I_{\text{ib+}}$	Non Inverting Input Bias Current DC current necessary to bias the input +	$\mathsf{T}_{\mathsf{amb}}$		26	55	μA
		T_{min} < T_{amb} < T_{max}		21		
I_{ib}	Inverting Input Bias Current DC current necessary to bias the input -	$\mathsf{T}_{\mathsf{amb}}$		$\overline{7}$	22	μ A
		$T_{min.} < T_{amb} < T_{max.}$		13		
CMR	Common Mode Rejection Ratio	$\Delta V_{\text{ic}} = \pm 1V$	50	54		dB
	20 log $(\Delta V_{ic}/\Delta V_{io})$	$T_{min.} < T_{amb} < T_{max.}$		54		
SVR	Supply Voltage Rejection Ratio	$\overline{\Delta V_{cc}}$ = 3.5V to 5V	63	74		dВ
	20 log $(\Delta V_{cc}/\Delta V_{out})$	$T_{min.} < T_{amb} < T_{max.}$		67		
PSR	Power Supply Rejection Ratio	ΔV_{cc} =200mVp-p@1kHz		56		dB
	20 log $(\Delta V_{cc}/\Delta V_{out})$	$T_{min.} < T_{amb} < T_{max.}$		52		
ICC	Supply Current DC consumption with no input signal	No load		16.6	20.2	mA
		T_{min} < T_{amb} < T_{max}		16.6		mA
	Dynamic performance and output characteristics					
R_{OL}	Transimpedance Output Voltage/Input Current Gain in open loop of a CFA. For a VFA, the analog of this feature is the Open Loop Gain (A _{VD})	$\Delta V_{\text{out}} = \pm 1 V$, R _L = 100 Ω	104	153		kΩ
		$T_{min} < T_{amb} < T_{max}$				
				152		k Ω
Bw	-3dB Bandwidth	Vout=20mVp-p, $RL = 100\Omega$				MHz
	Frequency where the gain is 3dB below the DC gain A_V	$A_V = +1$ $A_V = +2$		1500 1100 630		
	Note: Gain Bandwidth Product criterion is	$A_V = -4$	550			
	not applicable for Current-Feedback- Amplifiers	$A_V = -4$, $T_{min.} < T_{amb} < T_{max.}$		600		
	Gain Flatness @ 0.1dB	Small Signal V _{out} =20mVp-p				
	Band of frequency where the gain varia- tion does not exceed 0.1dB	$A_V = +2$, RL = 100 Ω		160		
SR	Slew Rate Maximum output speed of sweep in large signal	$V_{\text{out}} = 2Vp-p, A_V = +2,$		1800		
		$R_1 = 100\Omega$				$V/\mu s$
V_{OH}	High Level Output Voltage	$R_L = 100\Omega$	1.5	1.64		V
		$T_{min.} < T_{amb} < T_{max.}$		1.54		
V_{OL}	Low Level Output Voltage	$R_1 = 100\Omega$		-1.55	-1.5	V

Table 3. Electrical characteristics for V_{CC}= ±2.5Volts, T_{amb}=+25°C (unless otherwise specified)

Table 4. Closed-loop gain and feedback components

Figure 1. Frequency response, positive gain

Figure 2. Gain flatness, gain=+4

Figure 3. Compensation, gain=+2

57

Figure 4. Frequency response, negative gain

Figure 5. Gain flatness, gain=+2

Figure 6. Compensation, gain=+4

Figure 7. Compensation, gain=+10

Figure 10. Quiescent current vs. Vcc

Figure 11. Input voltage noise vs. frequency

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Figure 13. Output amplitude vs. frequency

Figure 14. Distortion vs. amplitude

57

Figure 16. Distortion vs. amplitude

Figure 19. Slew rate

Figure 20. Reverse isolation vs. frequency

Figure 22. CMR vs. temperature

Figure 23. SVR vs. temperature

Figure 24. ROL vs. temperature

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Figure 25. I-bias vs. temperature

Figure 26. Vio vs. temperature

S77

Figure 28. Icc vs. temperature

Figure 29. Iout vs. temperature

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3 Evaluation Boards

An evaluation board kit optimized for high-speed operational amplifiers is available (order code: KITHSEVAL/STDL). The kit includes the following evaluation boards, as well as a CD-ROM containing datasheets, articles, application notes and a user manual:

- SOT23 SINGLE HF BOARD: Board for the evaluation of a single high-speed op-amp in SOT23-5 package.
- SO8_SINGLE_HF: Board for the evaluation of a single high-speed op-amp in SO8 package.
- SO8_DUAL_HF: Board for the evaluation of a dual high-speed op-amp in SO8 package.
- SO8_S_MULTI: Board for the evaluation of a single high-speed op-amp in SO8 package in inverting and non-inverting configuration, dual and single supply.
- SO14 TRIPLE: Board for the evaluation of a triple high-speed op-amp in SO14 package with video application considerations.

Board material:

- 2 layers
- FR4 $(Er=4.6)$
- \bullet epoxy 1.6mm
- \bullet copper thickness: 35 μ m

Figure 30. Evaluation kit for high-speed op-amps

4 Power Supply Considerations

Correct power supply bypassing is very important for optimizing performance in high-frequency ranges. Bypass capacitors should be placed as close as possible to the IC pins to improve high-frequency bypassing. A capacitor greater than 1μ F is necessary to minimize the distortion. For better quality bypassing, a capacitor of 10nF can be added using the same implementation conditions. Bypass capacitors must be incorporated for both the negative and the positive supply.

For example, on the SO8_SINGLE_HF board, these capacitors are C6, C7, C8, C9.

Figure 31. Circuit for power supply bypassing

Single power supply

57

In the event that a single supply system is used, new biasing is necessary to assume a positive output dynamic range between 0V and $+V_{CC}$ supply rails. Considering the values of VoH and VoL, the amplifier will provide an output dynamic from +0.9V to +4.1V on 100Ω load.

The amplifier must be biased with a mid-supply (nominally $+V_{CC}/2$), in order to maintain the DC component of the signal at this value. Several options are possible to provide this bias supply, such as a virtual ground using an operational amplifier or a two-resistance divider (which is the cheapest solution). A high resistance value is required to limit the current consumption. On the other hand, the current must be high enough to bias the non-inverting input of the amplifier. If we consider this bias current (55µA max.) as the 1% of the current through the resistance divider to keep a stable mid-supply, two resistances of 470 $Ω$ can be used.

The input provides a high pass filter with a break frequency below 10Hz which is necessary to remove the original 0 volt DC component of the input signal, and to fix it at $+V_{\text{CC}}/2$.

[Figure](#page-11-0) 32 illustrates a 5V single power supply configuration for the SO8_SINGLE evaluation board (see [Evaluation Boards](#page-9-0) on page 10).

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A capacitor C_G is added in the gain network to ensure a unity gain in low-frequency to keep the right DC component at the output. C_G contributes to a high-pass filter with R_{fb}/R_G and its value is calculated with a consideration of the cut off frequency of this low-pass filter.

5 Noise Measurements

The noise model is shown in [Figure](#page-12-0) 33, where:

- eN: input voltage noise of the amplifier
- iNn: negative input current noise of the amplifier
- iNp: positive input current noise of the amplifier

Figure 33. Noise model

The thermal noise of a resistance R is:

4kTR∆F

where ∆F is the specified bandwidth.

477

On a 1Hz bandwidth the thermal noise is reduced to

 $\sqrt{4kTR}$

where k is the Boltzmann's constant, equal to 1,374.10-23J/°K. T is the temperature (°K).

The output noise eNo is calculated using the Superposition Theorem. However eNo is not the simple sum of all noise sources, but rather the square root of the sum of the square of each noise source, as shown in[Equation 1](#page-12-1):

$$
eNo = \sqrt{{v1}^{2} + {v2}^{2} + {v3}^{2} + {v4}^{2} + {v5}^{2} + {v6}^{2}}
$$
 Equation 1

$$
eNo^2 = eN^2 \times g^2 + iNn^2 \times R2^2 + iNp^2 \times R3^2 \times g^2 + \frac{R2^2}{R1} \times 4kTR1 + 4kTR2 + 1 + \frac{R2^2}{R1} \times 4kTR3 \quad Equation \ 2
$$

The input noise of the instrumentation must be extracted from the measured noise value. The real output noise value of the driver is:

$$
eNo = \sqrt{(Measured)^2 - (instrumentation)^2}
$$
 Equation 3

The input noise is called the Equivalent Input Noise as it is not directly measured but is evaluated from the measurement of the output divided by the closed loop gain (eNo/g).

After simplification of the fourth and the fifth term of *[Equation 2](#page-12-2)* [w](#page-13-0)e obtain:

Equation 4 $eNo^2 = eN^2 \times g^2 + iNn^2 \times R2^2 + iNp^2 \times R3^2 \times g^2 + g \times 4kTR2 + 1 + \frac{R2}{R}$ = $eN^2 \times g^2 + iNn^2 \times R2^2 + iNp^2 \times R3^2 \times g^2 + g \times 4kTR2 + 1 + \frac{R2^2}{R1} \times 4kTR3$

Measurement of the Input Voltage Noise eN

If we assume a short-circuit on the non-inverting input (R3=0), from *Equation 4* we can derive:

eNo = $\sqrt{eN^2 \times g^2 + iNn^2 \times R2^2} + g \times 4kTR2$

Equation 5

S7

In order to easily extract the value of eN, the resistance R2 will be chosen to be as low as possible. In the other hand, the gain must be large enough:

R3=0, gain: g=100

Measurement of the Negative Input Current Noise iNn

To measure the negative input current noise iNn, we set R3=0 and use *Equation 5*. This time the gain must be lower in order to decrease the thermal noise contribution:

R3=0, gain: g=10

Measurement of the Positive Input Current Noise iNp

To extract iNp from *Equation 3*, a resistance R3 is connected to the non-inverting input. The value of R3 must be chosen in order to keep its thermal noise contribution as low as possible against the iNp contribution: **Measurement of the Input Voltage Noise eN**

If we assume a short-circuit on the non-inverting input (R3=0), from Equation 4 we can derive:

If we assume a short-circuit on the non-inverting input (R3=0), from Equation 4

R3=100W, gain: g=10

6 Intermodulation Distortion Product

The non-ideal output of the amplifier can be described by the following series:

$$
Vout = C_0 + C_1 V_{in} + C_2 V^2 in + ... C_n V^n in
$$

due to non-linearity in the input-output amplitude transfer, where the input is $V_{in} = Asin \omega t$, C₀ is the DC component, $\rm C_1(V_{in})$ is the fundamental and $\rm C_n$ is the amplitude of the harmonics of the output signal $\rm V_{out}$.

A one-frequency (one-tone) input signal contributes to harmonic distortion. A two-tone input signal contributes to harmonic distortion and to the intermodulation product.

The study of the intermodulation and distortion for a two-tone input signal is the first step in characterizing the driving capability of multi-tone input signals.

In this case:

$$
V_{in} = A \sin \omega_1 t + A \sin \omega_2 t
$$

then:

57

$$
V_{in} = A\sin\omega_1 t + A\sin\omega_2 t
$$

$$
V_{out} = C_0 + C_1 (A\sin\omega_1 t + A\sin\omega_2 t) + C_2 (A\sin\omega_1 t + A\sin\omega_2 t)^2 ... + C_n (A\sin\omega_1 t + A\sin\omega_2 t)^n
$$

From this expression, we can extract the distortion terms, and the intermodulation terms form a single sine wave: second-order intermodulation terms IM2 by the frequencies $(\omega_1-\omega_2)$ and $(\omega_1+\omega_2)$ with an amplitude of C2A² and third-order intermodulation terms IM3 by the frequencies $(2\omega_1-\omega_2)$, $(2\omega_1+\omega_2)$, $(-\omega_1-\omega_2)$ ω₁+2ω₂) and (ω₁+2ω₂) with an amplitude of (3/4)C3A³.

The measurement of the intermodulation product of the driver is achieved by using the driver as a mixer by a summing amplifier configuration (see Figure 34). In this way, the non-linearity problem of an external mixing device is avoided.

S77

7 The Bias of an Inverting Amplifier

A resistance is necessary to achieve a good input biasing, such as resistance R shown in [Figure](#page-15-0) 35.

The magnitude of this resistance is calculated by assuming the negative and positive input bias current. The aim is to compensate for the offset bias current, which could affect the input offset voltage and the output DC component. Assuming Ib-, Ib+, Rin, Rfb and a zero volt output, the resistance R will be:

$$
R = \frac{R_{in} \times R_{fb}}{R_{in} + R_{fb}}
$$

R Load Output Rfb Ib- Rin Ib+ Vcc+ Vcc- + _ Obsolete Product(s)

Figure 35. Compensation of the input bias current

8 Active Filtering

Figure 36. Low-pass active filtering, Sallen-Key

From the resistors R_{fb} and R_G we can directly calculate the gain of the filter in a classical non-inverting amplification configuration:

$$
A_V = g = 1 + \frac{R_{fb}}{R_g}
$$

We assume the following expression as the response of the system

$$
T_{j\omega} = \frac{V \text{out}_{j\omega}}{V \text{in}_{j\omega}} = \frac{g}{1 + 2\zeta \frac{j\omega}{\omega_c} + \frac{(j\omega)^2}{\omega_c^2}}
$$

The cut-off frequency is not gain-dependent and so becomes:

$$
\omega_{\rm C} = \frac{1}{\sqrt{R1R2C1C2}}
$$

The damping factor is calculated by the following expression:

$$
\zeta = \frac{1}{2} \omega_{\mathbf{C}} (\mathbf{C}_1 \mathbf{R}_1 + \mathbf{C}_1 \mathbf{R}_2 + \mathbf{C}_2 \mathbf{R}_1 - \mathbf{C}_1 \mathbf{R}_1 \mathbf{g})
$$

The higher the gain, the more sensitive the damping factor is. When the gain is higher than 1, it is preferable to use some very stable resistor and capacitor values. In the case of R1=R2=R:

$$
\zeta = \frac{2C_2 - C_1 \frac{R_{fb}}{R_g}}{2\sqrt{C_1 C_2}}
$$

Due to a limited selection of values of capacitors in comparison with resistors, we can fix C1=C2=C, so that:

$$
\zeta = \frac{2R_2 - R_1 \frac{R_{fb}}{R_g}}{2\sqrt{R_1 R_2}}
$$

9 Package Mechanical Data

57

10 Revision History

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57